



N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Product Summary

V _{(BR)DSS}	R _{DS(ON)}	Package	I _{D max} T _A = +25°C
	52mΩ @ V _{GS} = 10V		
30V	65mΩ @ V _{GS} = 4.5V	SOT323	4A
	85mΩ @ V _{GS} = 2.5V		

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Applications

- DC-DC Converters
- Power Management Functions
- · Battery Operated Systems and Solid-State Relays

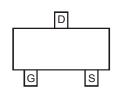
Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe.
 Solderable per MIL-STD-202, Method 208 3
- Terminal Connections: See Diagram
- Weight: 0.006 grams (approximate)

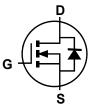
SOT323



Top View



Pin Configuration Top View



Equivalent CircuitI

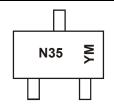
Ordering Information (Note 4)

Part Number	Case	Packaging
DMN3065LW-7	SOT323	3000/Tape & Reel
DMN3065LW-13	SOT323	10000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



N35 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: A = 2013) M = Month (ex: 9 = September)

Date Code Key

2012	2013		2014	20	15	2016		2017	2	2018
Z	Α		В			D		Е		F
an Feb	Mar	Anr	May	Jun	Jul	Aug	Sen	Oct	Nov	Dec
1 2	3	4	5	6	7	8	9	0	N	D
		Z A	Z A	Z A B	Z A B (Z A B C	Z A B C D	Z A B C D	Z A B C D E	Z A B C D E an Feb Mar Apr May Jun Jul Aug Sep Oct Nov



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain Source Voltage	V _{DSS}	30	V
Gate-Source Voltage	V _{GSS}	±12	V
Drain Current (Note 5)	I _D	4	Α
Body-Diode Continuous Current (Note 5)	Is	1	Α

Thermal Characteristics

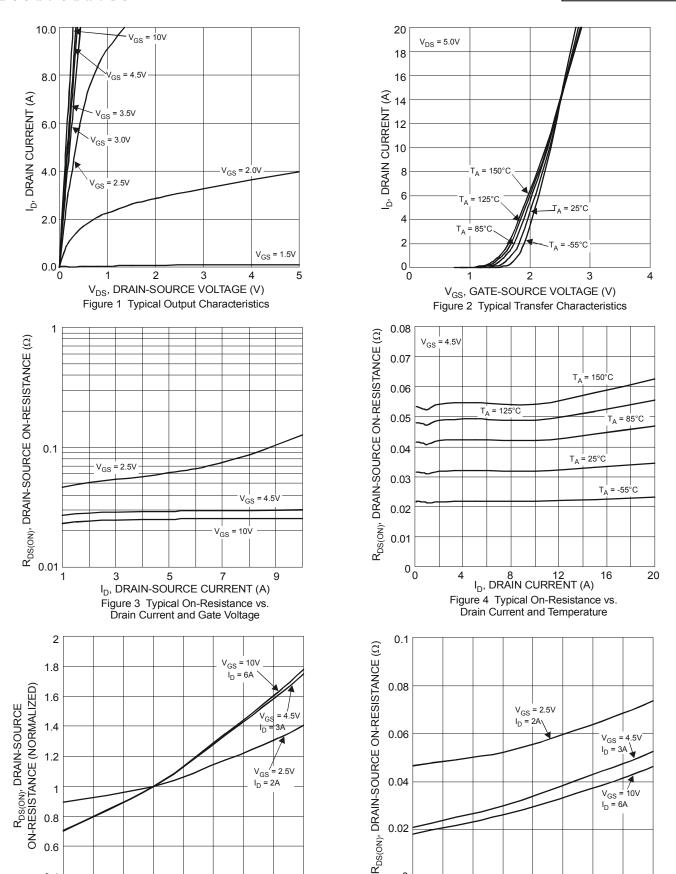
Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	P_{D}	770	mW	
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5)	$R_{\theta JA}$	162	°C/W	
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)	<u> </u>				ı		
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	V _{GS} = 0V, I _D = 250μA	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	V _{DS} = 30V, V _{GS} = 0V	
Gate-Body Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							
Gate Threshold Voltage	V _{GS(th)}	0.5	_	1.5	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
			_	52		$V_{GS} = 10V, I_D = 4A$	
Static Drain-Source On-Resistance	R _{DS} (ON)	_	_	65	mΩ	$V_{GS} = 4.5V, I_D = 3A$	
			_	85		$V_{GS} = 2.5V, I_D = 2A$	
Source-Drain Diode Forward Voltage	V_{SD}	_	_	1.2	V	$V_{GS} = 0V, I_{S} = 2.0A$	
DYNAMIC CHARACTERISTICS(7)							
Input Capacitance	Ciss	_	465	_	pF	VDS = 15V, VGS = 0V, f =	
Output Capacitance	Coss	_	49.5	_	pF		
Reverse Transfer Capacitance	Crss	_	43.8	_	pF	71.010112	
Gate Resistance	R _g	_	2.3	_	Ω	V_{DS} =0V, V_{GS} = 0V, f = 1MHz	
Total Gate Charge (V _{GS} =10V)	Qg	_	11.7	_	nC	V _{DS} = 15V, I _D = 4 A	
Total Gate Charge (V _{GS} =4.5V)	Qg	_	5.5	_	nC		
Gate-Source Charge	Q _{gs}	_	1.1	_	nC	V _{DS} = 15V, I _D = 4 A	
Gate-Drain Charge	Q_{gd}	_	1.8	_	nC		
Turn-On Delay Time	t _{D(on)}	_	1.9	_	ns		
Turn-On Rise Time	tr	_	1.6	_	ns	V _{DD} = 15V, V _{GEN} = 10V,	
Turn-Off Delay Time	t _{D(off)}	_	10.3		ns	$R_{GEN} = 3\Omega$, $R_L = 3.75\Omega$	
Turn-Off Fall Time	t _f	_	2.0	_	ns		

 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to production testing. Notes:





50

 T_J , JUNCTION TEMPERATURE (°C)

75

100

125

25

0

25

50

T_{.I}, JUNCTION TEMPERATURE (°C)

Figure 5 On-Resistance Variation with Temperature

75

100

125

150

0.4 -50

0

-50

150



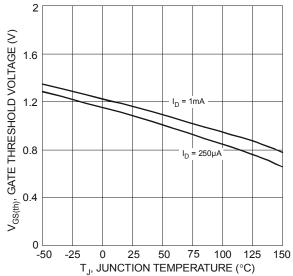
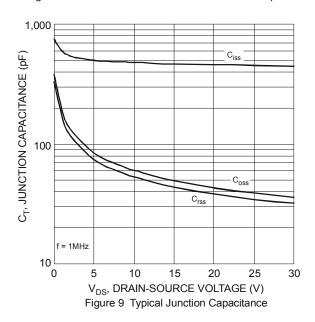
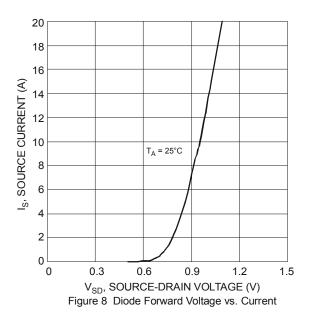
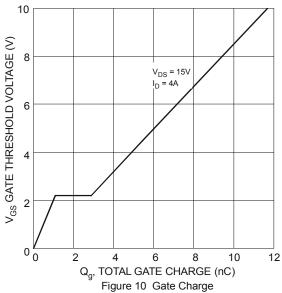


Figure 7 Gate Threshold Variation vs. Ambient Temperature

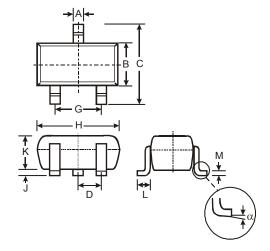






Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

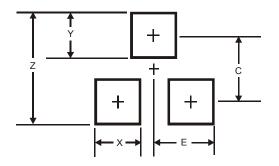


SOT323						
Dim	Min	Max	Тур			
Α	0.25	0.40	0.30			
В	1.15	1.35	1.30			
С	2.00	2.20	2.10			
D	-	-	0.65			
G	1.20	1.40	1.30			
Н	1.80	2.20	2.15			
J	0.0	0.10	0.05			
K	0.90	1.00	1.00			
L	0.25	0.40	0.30			
M	0.10	0.18	0.11			
α	0°	8°	-			
All	All Dimensions in mm					



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
Z	2.8			
Х	0.7			
Υ	0.9			
С	1.9			
E	1.0			

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